# Silicon Carbide Schottky Diode

# 650 V, 4 A

# FFSP0465A

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

#### Features

- Max Junction Temperature 175°C
- Avalanche Rated 25 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- This Device is Pb–Free, Halogen Free/BFR Free and RoHS Compliant

### Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

### **ABSOLUTE MAXIMUM RATINGS**

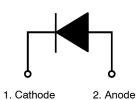
Symbol	Para	FFSP0465A	Unit		
V <sub>RRM</sub>	Peak Repetitive Reve	650	V		
E <sub>AS</sub>	Single Pulse Avalance	25	mJ		
١ <sub>F</sub>	Continuous Rectified @ T <sub>C</sub> < 163°C	4	A		
	Continuous Rectified @ T <sub>C</sub> < 135°C	8.6			
I <sub>F, Max</sub>	Non-Repetitive Peak Forward	$T_{C} = 25^{\circ}C$ , 10 µs	360	A	
	Surge Current	T <sub>C</sub> = 150°C, 10 μs	330		
I <sub>F, SM</sub>	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	38	A	
I <sub>F, RM</sub>	Repetitive Forward Surge Current	Half–Sine Pulse, t <sub>p</sub> = 8.3 ms	18	A	
Ptot	Power Dissipation	$T_C = 25^{\circ}C$	75	W	
		$T_C = 150^{\circ}C$	12.5		
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storag	–55 to +175	°C		
1. $E_{AS}$ of 25 mJ is based on starting $T_J$ = 25°C, L = 0.5 mH, $I_{AS}$ = 10 A, V = 50 V.					

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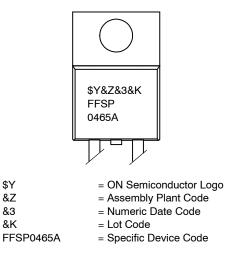
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### ELECTRICAL CONNECTION





#### MARKING DIAGRAM



#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

## FFSP0465A

#### THERMAL CHARACTERISTICS

Symbol	Parameter	Ratings	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	2.0	°C/W

#### PACKAGE MARKING AND ORDERING INFORMATION

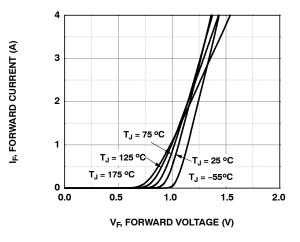
Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSP0465A	FFSP0465A	TO220	Tube	N/A	N/A	50 Units

## **ELECTRICAL CHARACTERISTICS** $T_C = 25^{\circ}C$ unless otherwise noted

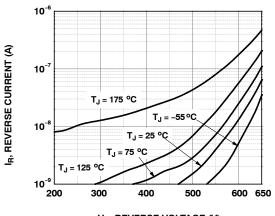
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>F</sub>	Forward Voltage	$I_F = 4 \text{ A}, \text{ T}_C = 25^{\circ}\text{C}$	-	1.50	1.75	V
		$I_{F} = 4 \text{ A}, \text{ T}_{C} = 125^{\circ}\text{C}$	-	1.6	2.0	
		$I_F = 4 \text{ A}, \text{ T}_C = 175^{\circ}\text{C}$	-	1.72	2.4	
I <sub>R</sub>	Reverse Current	$V_{R} = 650 \text{ V}, \text{ T}_{C} = 25^{\circ}\text{C}$	-	-	200	μΑ
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$	-	-	400	
		V <sub>R</sub> = 650 V, T <sub>C</sub> = 175°C	-	-	600	
$Q_{C}$	Total Capacitive Charge	V = 400 V	-	16	-	nC
С	Total Capacitance	V <sub>R</sub> = 1 V, f = 100 kHz	-	258	-	pF
		V <sub>R</sub> = 200 V, f = 100 kHz	-	29	-	
		V <sub>R</sub> = 400 V, f = 100 kHz	-	21	-	1

## FFSP0465A

#### **TYPICAL CHARACTERISTICS** $T_J = 25^{\circ}C$ Unless Otherwise Noted



**Figure 1. Forward Characteristics** 



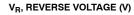
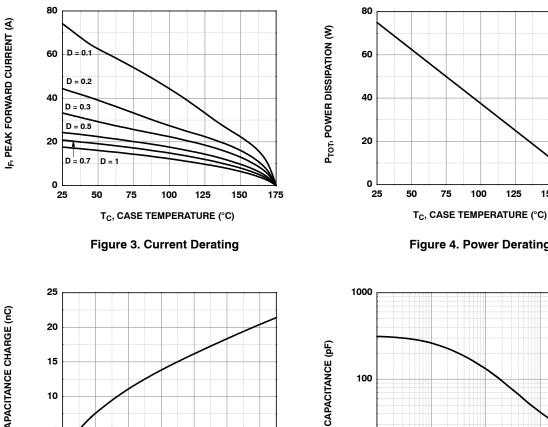
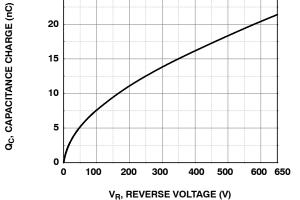


Figure 2. Reverse Characteristics







**Figure 4. Power Derating** 

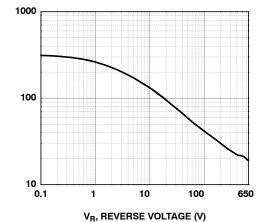
125

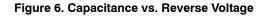
100

75

150

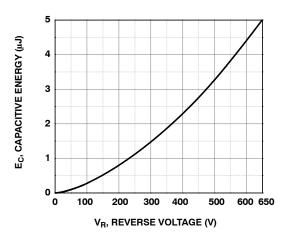
175

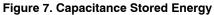


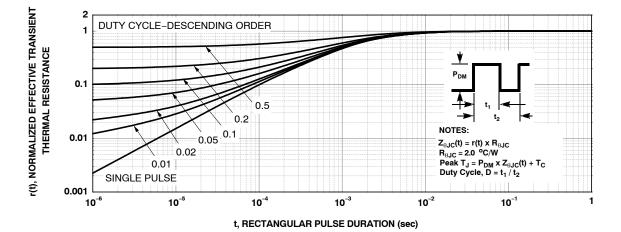


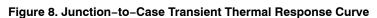
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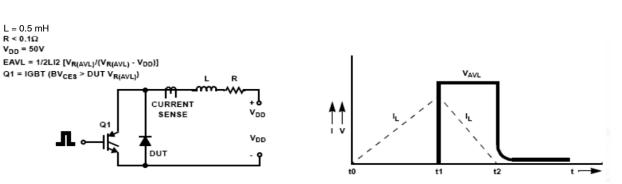
TYPICAL CHARACTERISTICS T<sub>J</sub> = 25°C Unless Otherwise Noted (continued)











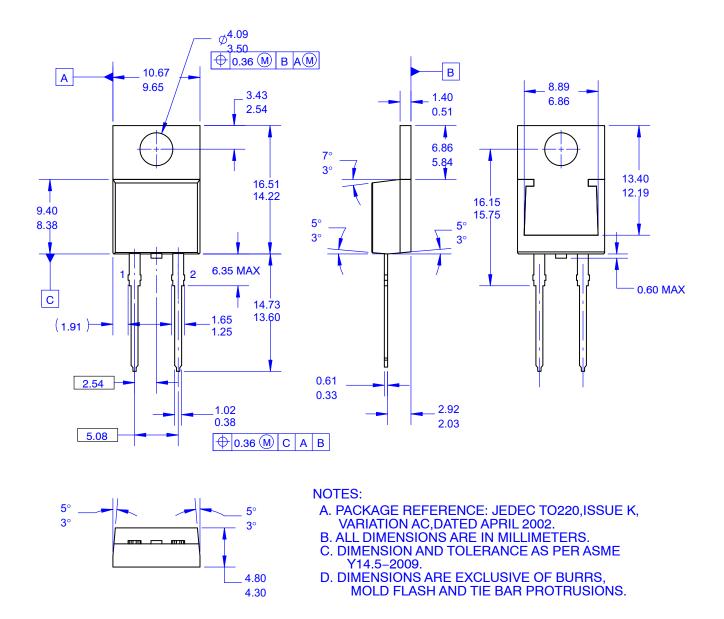
#### **TEST CIRCUIT AND WAVEFORMS**

Figure 9. Unclamped Inductive Switching Test Circuit & Waveform



TO-220-2LD CASE 340BB ISSUE O

DATE 31 AUG 2016



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